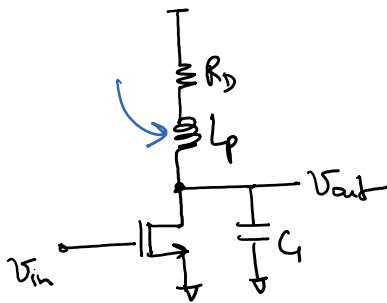


EE 513 - Lecture 22

Thursday, November 1, 2018 9:30 AM

Shunt Peaking:



$$A_v(s) = A_0 \cdot \frac{1 + s/\omega_z}{1 + \frac{s}{Q\omega_0} + \frac{s^2}{\omega_0^2}}$$

zero

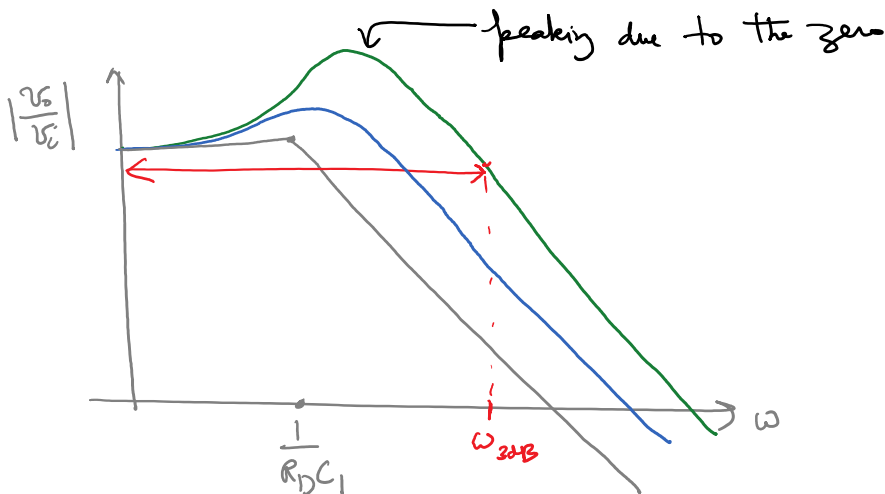
2nd-order system denominator
Q $\Rightarrow$ quality factor

$$A_0 = -g_m R_D$$

$$\omega_0 = \frac{1}{\sqrt{L_p C_1}}$$

$$\omega_z = \frac{R_D}{L_p} = \frac{\omega_0}{Q}$$

$$Q = \frac{1}{R_D} \sqrt{\frac{L_p}{C_1}}$$



$Q < 1$

* for maximally flat response $\Rightarrow Q = 0.63$

$$\rightarrow L_p = Q^2 R_D^2 C_1 = 0.4 R_D^2 C_1$$

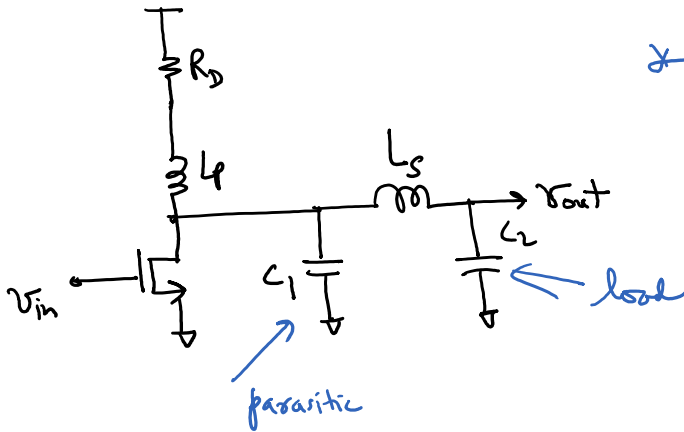
$\rightarrow$ Results in 70% increase in bandwidth (BW) compared to the case when $L_p = 0$.

* for a maximally flat group delay response even smaller Q is needed

$$\rightarrow L_p = 0.32 R_D^2 C_1$$

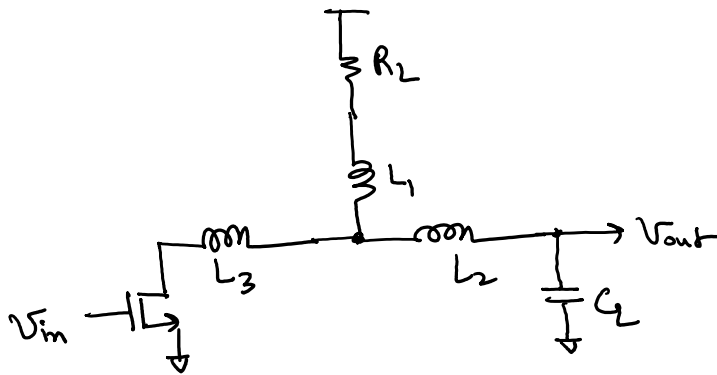
$\rightarrow$ BW extension is 60%

Shunt - Series peaking:



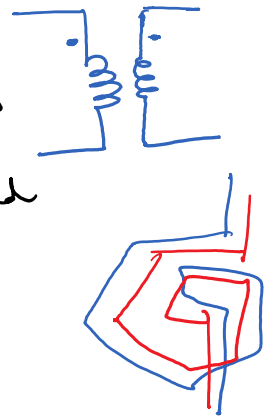
* Employing two inductors results in
2x BW compared to the original
amplifier
↳ 100% improvement

Shunt and Double Series peaking:

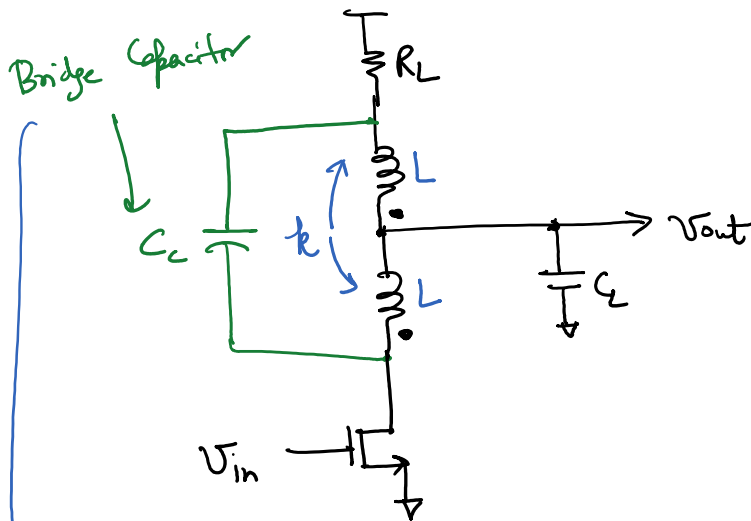


* $2\sqrt{2} \times$ bandwidth improvement
 $\rightarrow 183\%$

* To save die area, the combination of three inductors is realized using a pair of magnetically coupled inductors (i.e. a transformer)



$\rightarrow$ A T-coil



Design Equations:

$$L_1 = L_2 = \frac{R_L^2 C_L}{2(k+1)}$$

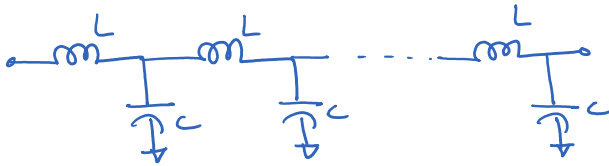
$$C_c = \frac{C_L}{4} \left[\frac{1-k}{1+k} \right]$$

$\rightarrow$ creates a parallel resonance with L 's

Distributed Amplifiers:

* Invented in 1936 by Parcival

Lossless Tline

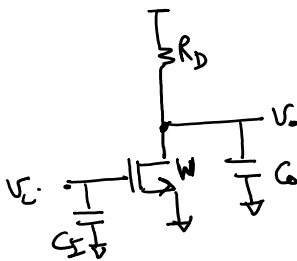


Characteristic impedance

$$Z_0 = \sqrt{\frac{L}{C}}$$

$$BW_{3dB} = \frac{1}{\pi \sqrt{LC}}$$

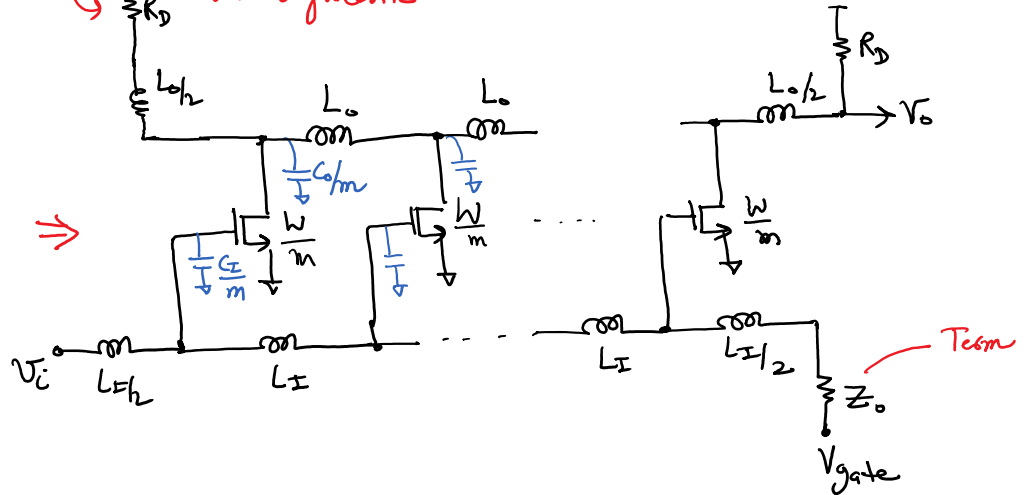
Lumped amplifier



$$\omega_p = \frac{1}{R_D C}$$

$$\omega_{un} = \frac{g_m}{C}$$

Term $\rightarrow$ m-segments



$$L_I = Z_0^2 \frac{C_I}{m} \quad \text{and} \quad L_O = R_D^2 \frac{C_O}{m} \quad \text{--- (1)}$$

$$Z_0 = \sqrt{\frac{L}{C}}$$

$$A_v = -m \left(\frac{g_{meff}}{m} \right) \frac{R_D}{2} = -g_{meff} \frac{R_D}{2}$$

$\therefore$ at very low frequencies the two R_D come in parallel.

* The bandwidth is given by

$$BW_{3dB} = \min \left\{ \frac{1}{\pi \sqrt{L_I C_I}}, \frac{1}{\pi \sqrt{L_O C_O}} \right\} \quad \text{--- (2)}$$

* Usually $C_i = C_o \Rightarrow$ if not equal, add extra capacitance in ...

Parallel

* If we set $R_D = Z_o$ then

$$BW_{3dB} = \min \left\{ \frac{m}{\pi R_D C_I}, \frac{m}{\pi R_D C_o} \right\}$$

① is substituted here in ②

$m \rightarrow \infty, BW_{3dB} \rightarrow \infty$ (ideally)

↳ ultimately limited by parasitics

↳ by f_{max} of the transistor

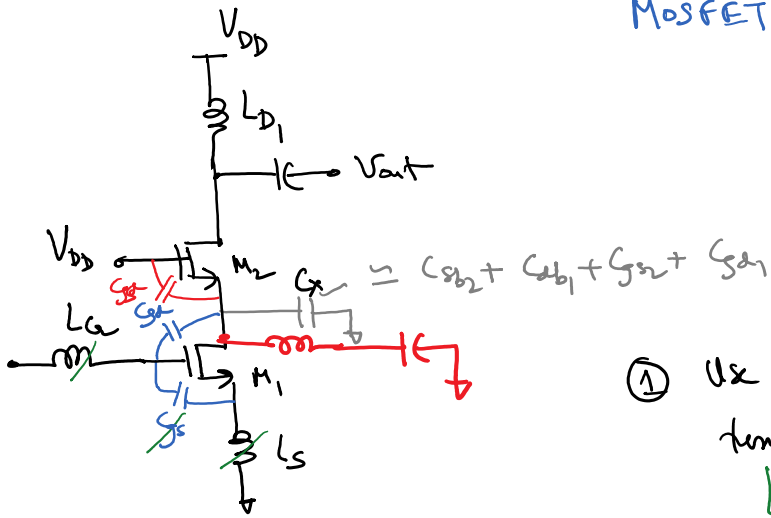
* f_T doubler

* Cherry-Hooper stage

} Book 4 T.H. Lee Book.

Design of mmWave LNAs :

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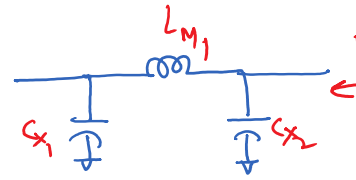
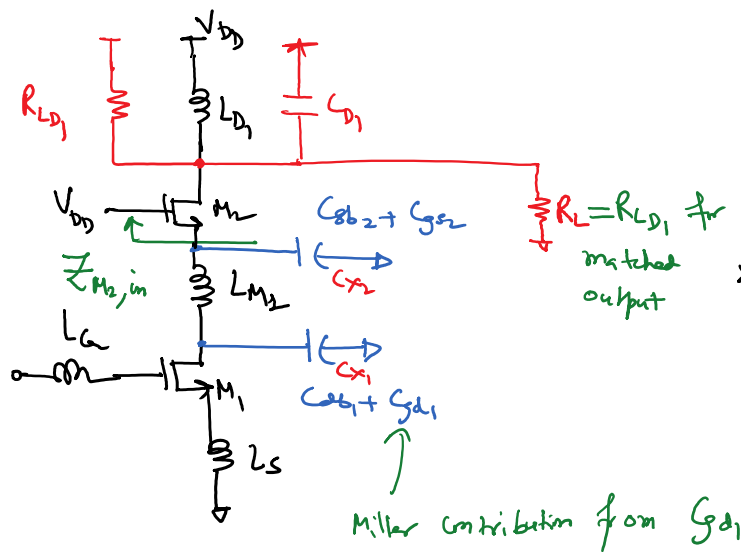
MOSFET

$G_d \leq 50\%$ of G_s

→ reduces the f_T of the transistor in cascode config by 33%.

① Use shunt inductor to AC ground to tune-out C_x

→ this resonance is narrowband



* The characteristic impedance of this artificial Tline can be expressed as

$$Z_0 = \sqrt{\frac{L_{M1}}{C_{GS2} + C_{GD2}}} \quad \therefore Z_0 = \sqrt{\frac{L}{C}}$$

* The 3dB BW when matched at both the ends becomes

$$f_{3dB} = \frac{1}{\pi \sqrt{L_{M1} (C_{GS2} + C_{GD2})}}$$

$$Z_{M2,in} = \frac{1}{g_{m2}} + \frac{R_{drain}}{g_{m2} \omega_2 + 1}$$

$$= \frac{1}{g_{m2}} + \frac{R_{LD1} \parallel R_L}{g_{m2} \omega_2 + 1}$$

$$= \frac{1}{g_{m2}} + \frac{1}{2} \cdot \frac{R_{LD1}}{g_{m2} \omega_2 + 1}$$

$$Z_{M2,in} = \frac{1}{g_{m2}} + \frac{1}{2} \cdot \frac{\omega_0 Q L_{D1}}{g_{m2} \omega_2 + 1}$$

Razavi's Analog Book

* ECE 410 / SIS Course

$$\therefore Q = \frac{R_p}{\omega_0 L_p}$$

$$\Rightarrow R_p = \omega_0 Q L_p$$

Set $Z_{O1} = \sqrt{\frac{L_{M1}}{C_{GS2} + C_{GD2}}} = Z_{M2,in}$

$L \rightarrow$ gives value for L_M .